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NZT902 NPN Low Saturation Transistor

· These devices are designed with high current gain and low saturation voltage with collector currents up to 3A continuous.



September 2006

1. Base 2. Collector 3. Emitter

Absolute Maximum Ratings* T_x=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CEO}	Collector-Emitter Voltage	90	V	
V _{CBO}	Collector-Base Voltage	120	V	
V _{EBO}	Emitter-Base Voltage	5	V	
I _C	Collector Current - Continuous	3	А	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature Range	- 55 ~ +150	°C	

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 150°C. 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics* $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units	
P _D	Total Device Dissipation	1	W	
R _{0JA} Thermal Resistance, Junction to Ambient		125	°C/W	

Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm.

Electrical Characteristics* $T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA	90			V
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = 100μA	120			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 100μA	5			V
I _{CBO}	Collector-Base Cutoff Current	V _{CB} = 100V V _{CB} = 100V, Ta = 100 °C			100 10	nA uA
I _{EBO}	Emitter-Base Cutoff Current	$V_{EB} = 4V$			100	nA
h _{FE}	DC Current Gain	$ I_{C} = 0.1A, V_{CE} = 2V \\ I_{C} = 1A, V_{CE} = 2V \\ I_{C} = 2A, V_{CE} = 2V \\ I_{C} = 2A, V_{CE} = 2V $	80 80 25			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$ \begin{array}{l} I_{C} = 0.1A, \ I_{B} = 5.0mA \\ I_{C} = 1A, \ I_{B} = 100mA \\ I_{C} = 3A, \ I_{B} = 300mA \end{array} $			50 250 600	mV mV mV
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 1A, I _B = 100mA			1.25	V
C _{obo}	Output Capacitance	V _{CB} = 10V, I _E = 0, f = 1MHz			35	pF
f _T	Transition Frequency	$I_{C} = 100 \text{mA}, V_{CE} = 5 \text{V}, f = 100 \text{MHz}$	75			MHz

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Typical Performance Characteristics

Figure 1. Static Characteristic

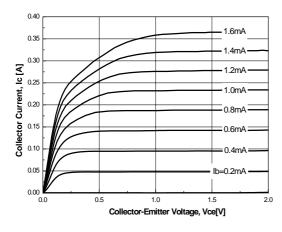


Figure 2. DC current Gain

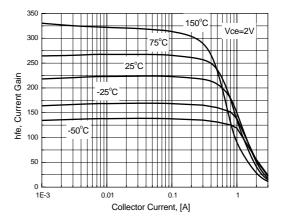
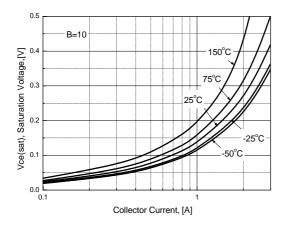
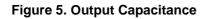


Figure 3. Collector-Emitter Saturation Voltage





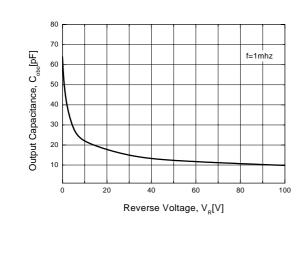


Figure 4. Base-Emitter Saturation Voltage

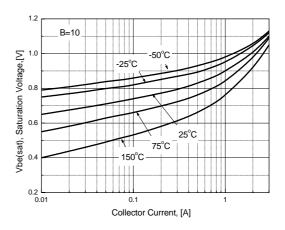
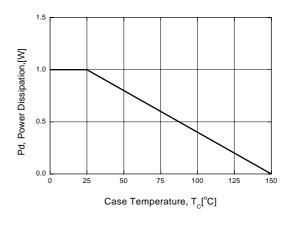
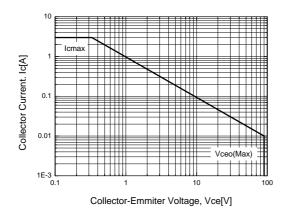


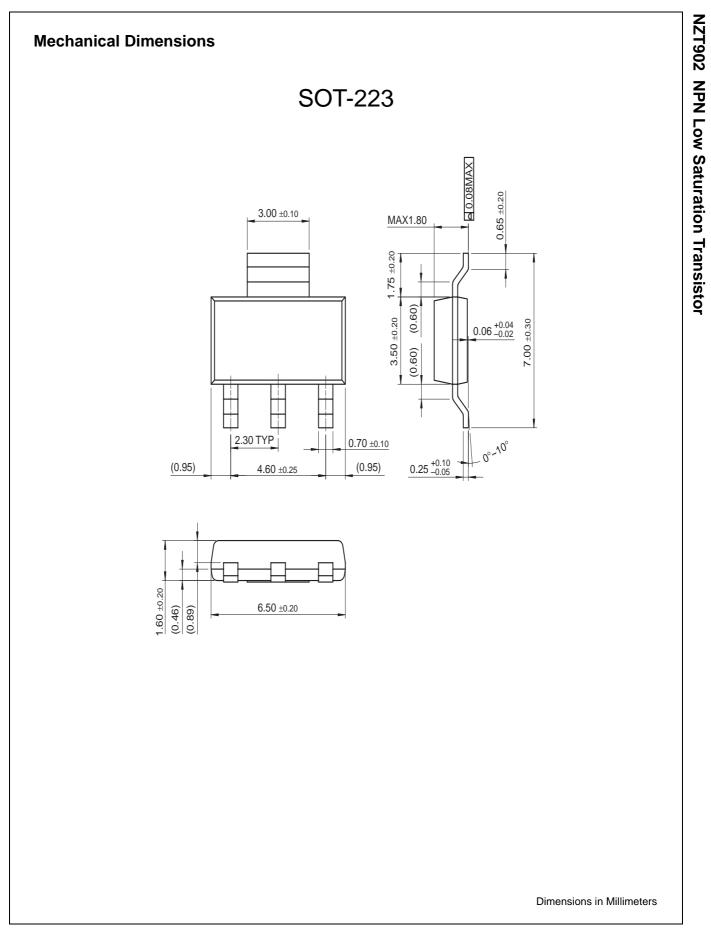
Figure 6. Power Dissipation vs Ambient Temperature



Typical Performance Characteristics

Figure 9. SOA





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